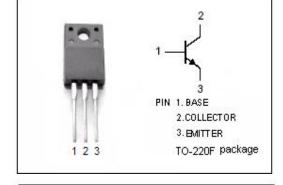


# **isc Silicon NPN Power Transistors**

**KTC4369** 

### **DESCRIPTION**

- · Low Saturation Voltage-
- :  $V_{CE(sat)}=0.8V(Max)@ (I_C=2A, I_B=0.2A)$
- · Collector-Emitter Sustaining Voltage-
  - :  $V_{CEO(SUS)} = 30V(Min)$
- Complement to Type KTA1658
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

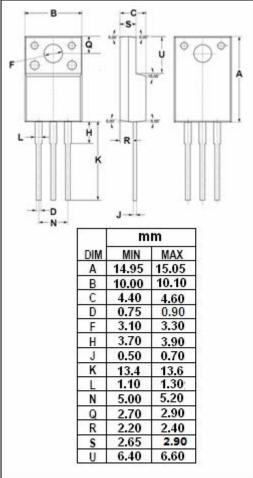


### **APPLICATIONS**

• Designed for use in general purpose applications .

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	30	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V	
V <sub>EBO</sub>	Emitter-Base Voltage 5			
Ic	Collector Current-Continuous 3		Α	
I <sub>B</sub>	Base Current 0.3		Α	
Pc	Collector Power Dissipation $T_C=25^{\circ}C$		W	
T <sub>j</sub>	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range -55~150		$^{\circ}\mathbb{C}$	





## **isc Silicon NPN Power Transistors**

**KTC4369** 

#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA; I <sub>B</sub> = 0	30			V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 0.2A			0.8	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 2V			1.0	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 20V; I <sub>E</sub> = 0			1	uA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1	uA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 2V	70		240	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 2.5A; V <sub>CE</sub> = 2V	25			
Сов	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V,f <sub>test</sub> = 1MHz		35		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 2V		100		MHz

## ♦ h<sub>FE-1</sub>Classifications

0	Y	
70-140	120-240	

Notice:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

2

isc website: <u>www.iscsemi.com</u>